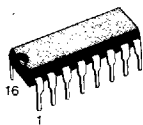
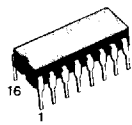


HEX D-TYPE FLIP-FLOP WITH CLEAR

- HIGH SPEED
 $f_{MAX} = 48 \text{ MHz (TYP.) at } V_{CC} = 5V$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu A \text{ (MAX.) at } T_A = 25^\circ C$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (MIN.)}$
- OUTPUT DRIVE CAPABILITY
 10 LSTTL LOADS
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} \text{ (OPR)} = 2V \text{ to } 6V$
- PIN AND FUNCTION COMPATIBLE
 WITH 54/74LS174


B1N
 Plastic Package

F1
 Ceramic Frit Seal Package

M1
 Micro Package

C1
 Plastic Chip Carrier

ORDERING NUMBERS:

 M54HC174 F1
 M74HC174 B1N
 M74HC174 F1




 M74HC174 C1
 M74HC174 M1

DESCRIPTION

The M54/74HC174 is a high speed CMOS HEX D-TYPE FLIP-FLOP WITH CLEAR fabricated in silicon gate CMOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

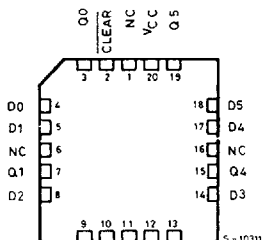
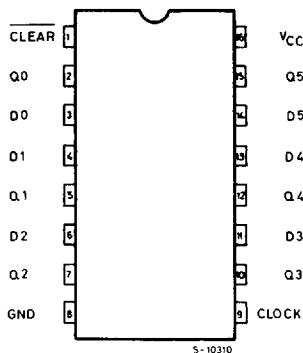
Information signals applied to D inputs are transferred to the Q output on the positive going edge of the clock pulse. When the CLEAR input is held low, the Q outputs are held low independently of the other inputs. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

TRUTH TABLE

INPUTS			OUTPUT	FUNCTION
CLEAR	D	CLOCK	Q	
L	X	X	L	CLEAR
H	L		L	—
H	H		H	—
H	X		Qn	NO CHANGE

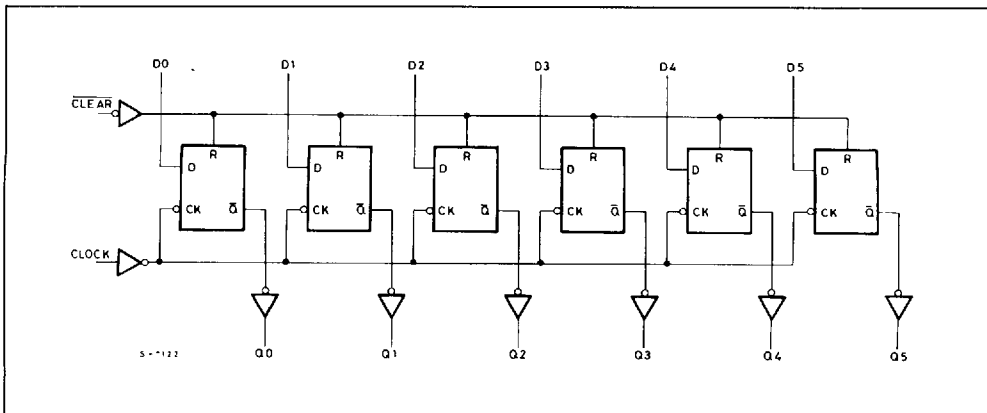
X: DON'T CARE

PIN CONNECTIONS (top view)


 NC =
 No Internal
 Connection

LOGIC DIAGRAM

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to 7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(*) 500 mW: $\cong 65^{\circ}C$ to 300 mW by 10 mW/ $^{\circ}C$: 65 to 85 $^{\circ}C$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit	
V_{CC}	Supply Voltage	2 to 6	V	
V_I	Input Voltage	0 to V_{CC}	V	
V_O	Output Voltage	0 to V_{CC}	V	
T_A	Operating Temperature	74HC Series 54HC Series	-40 to 85 -55 to 125	$^{\circ}C$
t_r, t_f	Input Rise and Fall Time	V_{CC} { 2 V 4.5V 6 V	0 to 1000 0 to 500 0 to 400	ns

DC ELECTRICAL CHARACTERISTICS

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Symbol	Parameter	V _{CC}	Test Condition	T _A = 25°C 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit	
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
V _{IH}	High Level Input Voltage	2.0 4.5 6.0		1.5 3.15 4.2	— — —	— — —	1.5 3.15 4.2	— — —	1.5 3.15 4.2	— — —	V	
V _{IL}	Low Level Input Voltage	2.0 4.5 6.0		— — —	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	V	
V _{OH}	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I	I _O	1.9	2.0	—	1.9	—	1.9	—	V
			V _{IH}	-20 μA	4.4	4.5	—	4.4	—	4.4	—	
			V _{IL}	-4.0 mA	4.18	4.31	—	4.13	—	4.10	—	
				-5.2 mA	5.68	5.8	—	5.63	—	5.60	—	
V _{OL}	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _{IH} or V _{IL}	20 μA	—	0.0	0.1	—	0.1	—	0.1	V
					—	0.0	0.1	—	0.1	—	0.1	
					—	0.0	0.1	—	0.1	—	0.1	
				4.0 mA	—	0.17	0.26	—	0.33	—	0.40	
	5.2 mA	—	0.18	0.26	—	0.33	—	0.40				
I _I	Input Leakage Current	6.0	V _I = V _{CC} or GND	—	—	±0.1	—	±1.0	—	±1.0	μA	
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{CC} or GND	—	—	4	—	40	—	80	μA	

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, T_A = 25°C, C_L = 15pF, Input t_r = t_f = 6ns)

Symbol	Parameter	54HC and 74HC			Unit
		Min.	Typ.	Max.	
t _{TLH} t _{THL}	Output Transition Time		4	8	ns
t _{PLH} t _{PHL}	Propagation Delay Time (CK-QH)		19	30	ns
t _{PHL}	Propagation Delay Time (CLEAR-QH)		19	30	ns
f _{MAX}	Maximum Clock Frequency	30	48		MHz

AC ELECTRICAL CHARACTERISTICS ($C_L = 50\text{pF}$, Input $t_r = t_f = 6\text{ns}$)

Symbol	Parameter	V_{CC}	Test Condition	$T_A = 25^\circ\text{C}$ 54HC and 74HC			-40 to 85°C 74HC		-55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
				t_{TLH} t_{THL}	Output Transition Time	2.0 4.5 6.0		— — —	30 8 7	75 15 13	
t_{PLH} t_{PHL}	Propagation Delay Time (CK - Q)	2.0 4.5 6.0		— — —	92 23 20	180 36 31	— — —	225 45 38		270 54 46	ns
t_{PHL}	Propagation Delay Time (CLEAR-Q)	2.0 4.5 6.0		— — —	92 23 20	180 36 31	— — —	225 45 38		270 54 46	ns
f_{MAX}	Maximum Clock Frequency	2.0 4.5 6.0		5 27 32	11 44 52	— — —	4 22 26	— — —	3 18 21	— — —	MHz
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width (CLOCK)	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16		110 22 19	ns
$t_{W(L)}$	Minimum Pulse Width CLEAR	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16		110 22 19	ns
t_s	Minimum Set-up Time	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16		110 22 19	ns
t_h	Minimum Hold Time	2.0 4.5 6.0		— — —	— — —	0 0 0	— — —	0 0 0	— — —	0 0 0	ns
t_{REM}	Minimum Removal Time CLEAR	2.0 4.5 6.0		— — —	16 4 3	75 15 13	— — —	95 19 16	— — —	110 22 19	ns
C_{IN}	Input Capacitance			—	5	10	—	10		10	pF
$C_{PD} (*)$	Power Dissipation Capacitance			—	53	—	—	—			pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

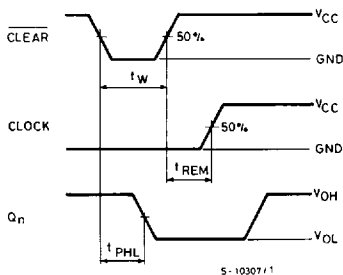
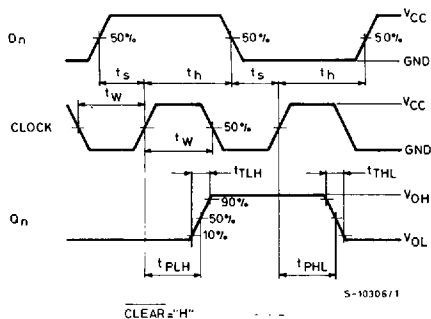
Average operating current is: $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per Flip-Flop)

And the total C_{PD} when N pcs of Flip-Flop operate can be gained by the following equation: $C_{PD}(\text{total}) = 38 + 15 \cdot n$

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SWITCHING CHARACTERISTICS TEST WAVEFORM

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TEST CIRCUIT I_{CC} (Opr.)